

BT155W-1200T-A

#### Automotive Grade SCR

Rev - 02 25 January 2019

#### **Product data sheet**

#### 1. General description

Planar passivated Silicon Controlled Rectifier in a TO-247 plastic package intended for use in applications requiring very high inrush current capability and high thermal cycling performance. This product is qualified to AEC-Q101 standard for use in automotive applications.



### 2. Features and benefits

- High thermal cycling performance
- Planar passivated for voltage ruggedness and reliability
- · High voltage capacity
- Very high current surge capability
- AEC-Q101 compliant

### 3. Applications

- Automotive battery charging (on-board and off-board)
- Solid State Relay (SSR)
- Uninterruptible Power Supply (UPS)
- Inrush protection and soft-start
- AC and DC motor controls
- Heating controls
- AC Power rectification
- Renewable energy inverters
- Industrial welding systems

### 4. Quick reference data

Table 1. Q	uick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Absolute	Absolute maximum rating							
$V_{\text{DRM}}$	repetitive peak off-state voltage			-	-	1200	V	
$V_{\text{RRM}}$	repetitive peak reverse voltage			-	-	1200	V	
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$ ; $t_p = 10 \text{ ms}$ ; Fig. 4; Fig. 5		-	-	650	A	
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms		-	-	715	А	
Tj	junction temperature			-	-	150	°C	
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_{mb} \le 131 \text{ °C}$		-	-	50	A	

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$I_{T(RMS)}$	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 131 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>		-	-	79	A
Static ch	aracteristics						
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 7; Fig. 8		-	-	50	mA
Dynamic	characteristics						
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 804 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 100 Ω; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform		1500	-	-	V/µs

### 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		
2	A	anode		А-₽+К
3	G	gate		с G
mb	A	mounting base; connected to anode		sym037

### 6. Ordering information

#### Table 3. Ordering information Type number Orderable part number Packing Small packing Package Package Package method issue date name quantity version BT155W-1200T-A BT155W-1200T-AQ TO-247 Tube 30 TO-247N 20-Jul-2016

### 7. Marking

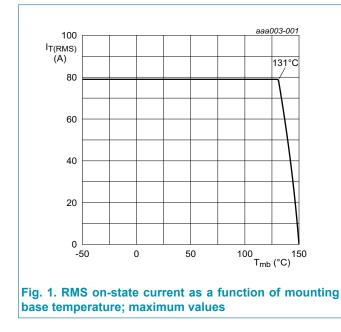
Table 4. Marking codes							
	Type number	Marking codes					
	BT155W-1200T-A	BT155W-1200T-A					

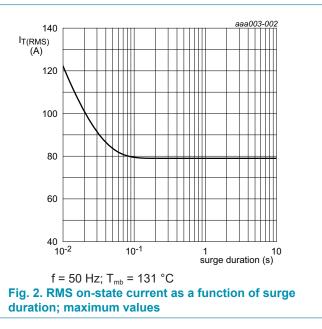
## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

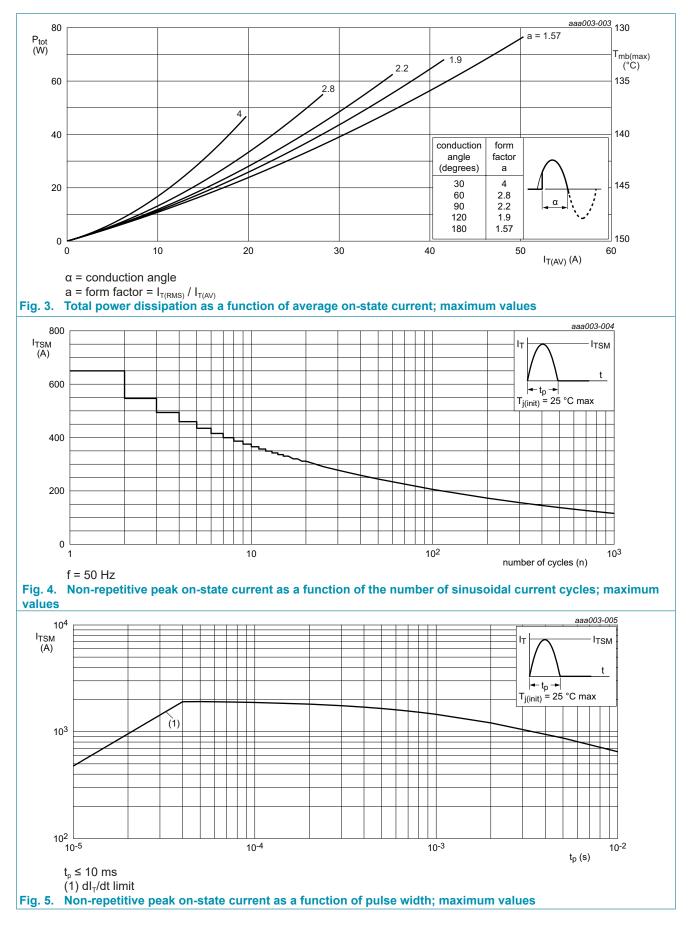
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	1200	V
$V_{\text{RRM}}$	repetitive peak reverse voltage		-	1200	V
$I_{T(AV)}$	average on-state current	half sine wave; T <sub>mb</sub> ≤ 131 °C	-	50	А
$I_{T(RMS)}$	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 131 °C; <u>Fig 1; Fig 2</u> ; <u>Fig 3</u>	-	79	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; <u>Fig 4; Fig 5</u>	-	650	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	715	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	-	2113	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 100mA	-	150	A/µs
I <sub>GM</sub>	peak gate current		-	8	А
$V_{\text{RGM}}$	peak reverse gate voltage		-	5	V
$P_{GM}$	peak gate power		-	20	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
T <sub>j</sub>	junction temperature		-	150	°C





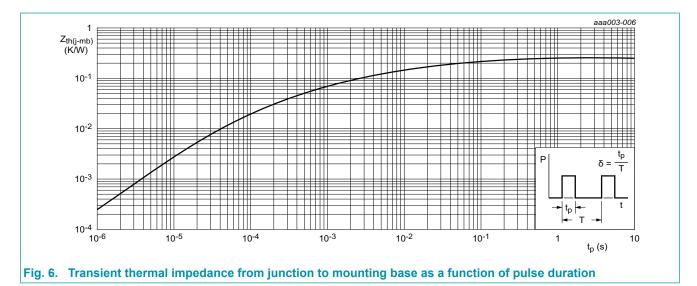
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### 9. Thermal characteristics

Table 6. Th	Fable 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	full cycle; <u>Fig 6</u>		-	-	0.25	K/W	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air		-	50	-	K/W	



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### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics	· · · ·				
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}_j = 25 \text{ °C};$ Fig. 7; Fig. 8	-	-	50	mA
I <sub>L</sub>	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 9	-	-	300	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	200	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 50 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	-	1.3	V
		I <sub>T</sub> = 90 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	-	1.5	V
V <sub>GT</sub>	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 12	-	0.7	1	V
		V <sub>D</sub> = 800 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C; Fig. 12	0.25	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 1200 V; T <sub>j</sub> = 125 °C	-	-	3	mA
I <sub>R</sub>	reverse current	V <sub>D</sub> = 1200 V; T <sub>j</sub> = 125 °C	-	-	3	mA
Dynamic	characteristics	· · ·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 804 \text{ V};  \text{T}_{\text{j}} = 125 ^{\circ}\text{C};  \text{R}_{\text{GK}} = 100  \Omega; \\ (\text{V}_{DM} = 67\% \text{ of } \text{V}_{\text{DRM}}); \text{ exponential} \\ \text{waveform}$	1500	-	-	V/µs
		$V_{DM} = 804 \text{ V};  \text{T}_{\text{j}} = 150 ^{\circ}\text{C};  \text{R}_{\text{GK}} = 100  \Omega; \\ (V_{DM} = 67\% \text{ of } V_{\text{DRM}}); \text{ exponential} \\ \text{waveform}$	1000	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$ I_{TM} = 40 \text{ A}; V_D = 800 \text{ V}; I_G = 0.1 \text{ A}; \text{ d}I_G \text{/} \\ \text{d}t = 5 \text{ A}/\mu\text{s}; T_j = 25 \ ^\circ\text{C} $	-	2	-	μs
t <sub>q</sub> commutated turn-off time			-	150	-	μs

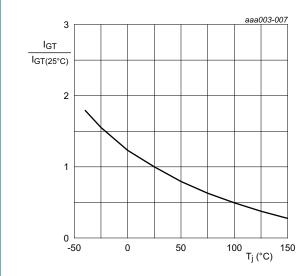
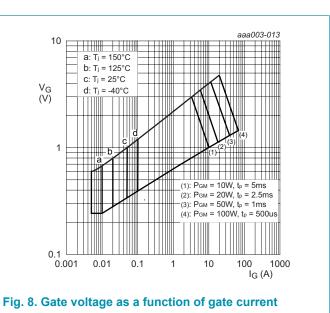


Fig. 7. Normalized gate trigger current as a function of junction temperature

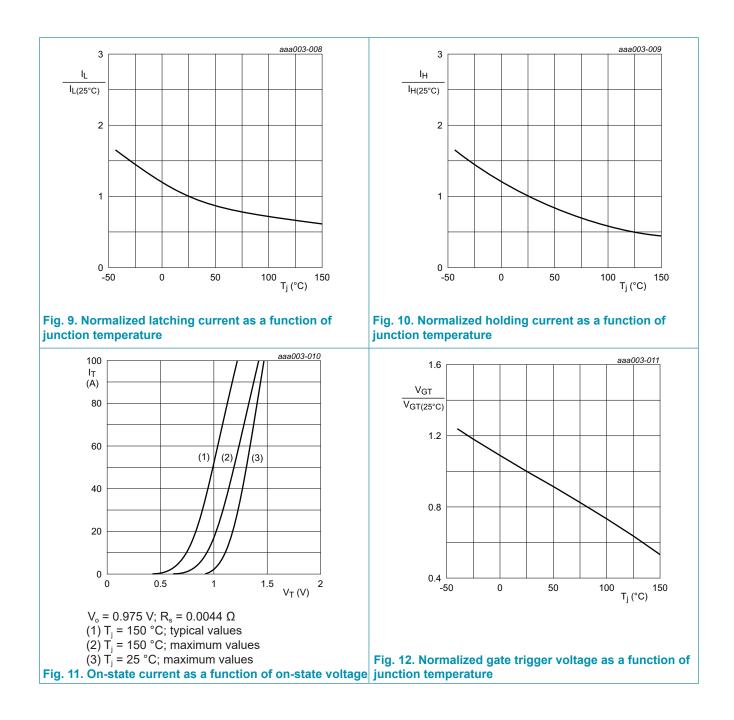


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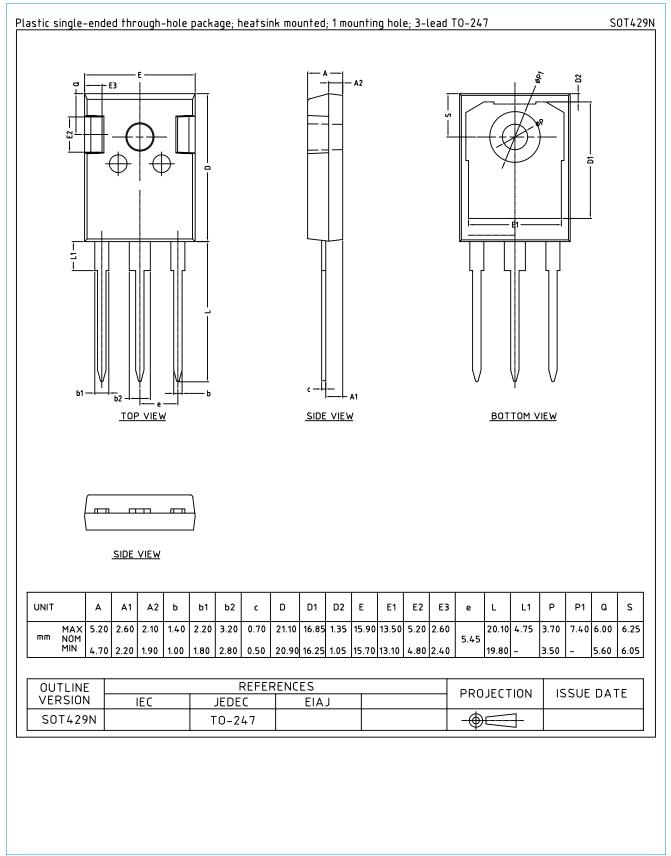
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### **11. Package outline**



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## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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